

High Speed IGBT4 Modules

SKM75GB12F4

Features*

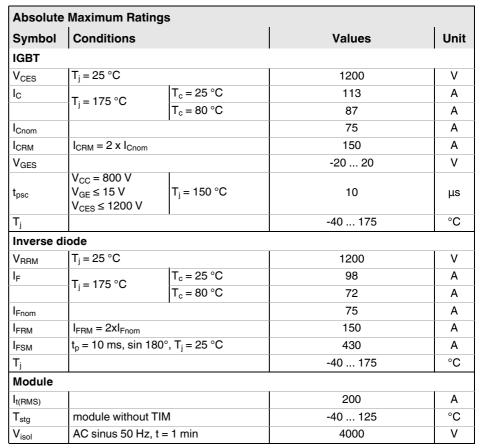
- · High speed trench and field-stop IGBT
- CAL4 ultra-fast = soft switching 4. generation CAL-diode
- Insulated copper baseplate using DBC technology (Direct Bonded Copper)
- · Increased power cycling capability
- For higher switching frequencies above 15kHz
- UL recognized, file no. E63532

Typical Applications

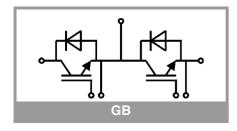
- UPS
- Electronic welders
- Inductive heating
- · Switched mode power supplies

Remarks

- Case temperature limited to T_c = 125°C max.
- Recommended T_{op} = -40 ... +150°C
- Product reliability results valid for T_i = 150°C



Characte	eristics					
Symbol	Conditions	min.	typ.	max.	Unit	
IGBT	•		•			
V _{CE(sat)}	$I_{\rm C} = 75 {\rm A}$	T _j = 25 °C		2.08	2.41	V
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.60	2.93	V
V _{CE0}	chiplevel	T _j = 25 °C		1.10	1.28	V
		T _j = 150 °C		0.95	1.13	V
r _{CE}	V _{GE} = 15 V chiplevel	T _j = 25 °C		13	15	mΩ
		T _j = 150 °C		22	24	mΩ
$V_{GE(th)}$	$V_{GE}=V_{CE}$, $I_{C}=2.6$ mA		5.2	5.8	6.4	V
I _{CES}	V _{GE} = 0 V, V _{CE} = 1200 V, T _j = 25 °C				1	mA
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		4.4		nF
Coes		f = 1 MHz		0.29		nF
C _{res}		f = 1 MHz		0.24		nF
Q_{G}	V _{GE} = - 8 V+ 15 V			425		nC
R _{Gint}	T _j = 25 °C			0		Ω
t _{d(on)}	$\begin{array}{c} V_{CC} = 600 \ V \\ I_{C} = 75 \ A \\ V_{GE} = +15/-15 \ V \\ R_{G \ on} = 6.2 \ \Omega \\ R_{G \ off} = 6.2 \ \Omega \\ di/dt_{on} = 3750 \ A/\mu s \\ di/dt_{off} = 1100 \ A/\mu s \\ dv/dt = 5370 \ V/\mu s \\ L_{s} = 25 \ nH \end{array}$	T _j = 150 °C		9		ns
t _r		T _j = 150 °C		21		ns
E _{on}		T _j = 150 °C		6.8		mJ
t _{d(off)}		T _j = 150 °C		285		ns
t _f		T _j = 150 °C		61		ns
E _{off}		T _j = 150 °C		5.3		mJ
R _{th(j-c)}	per IGBT			0.325	K/W	
$R_{th(c-s)}$	per IGBT (λ _{grease} =0		0.143		K/W	





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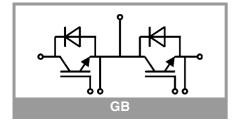
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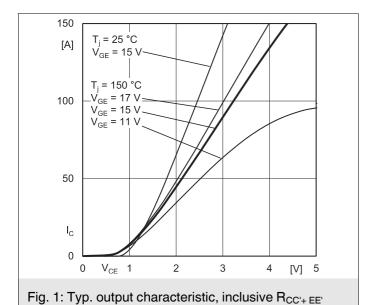
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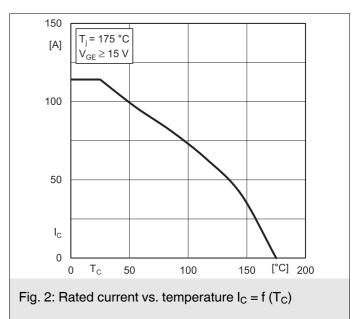
Remarks

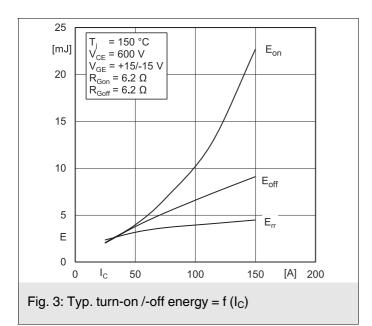
- · Case temperature limited to $T_c = 125$ °C max.
- Recommended $T_{op} = -40 \dots +150^{\circ}C$
- Product reliability results valid for $T_i = 150$ °C

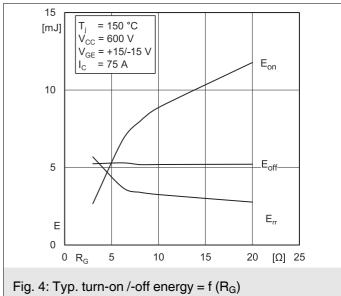
Characteristics									
Symbol	Conditions		min.	typ.	max.	Unit			
Inverse d	iode		•						
V _{GE} = 0 \	I _F = 75 A	T _j = 25 °C		2.43	2.80	V			
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.29	2.65	V			
V _{F0}	chiplevel	T _j = 25 °C		1.51	1.75	V			
		T _j = 150 °C		1.16	1.40	V			
r _F	chiplevel	T _j = 25 °C		12	14	mΩ			
		T _j = 150 °C		15	17	mΩ			
I _{RRM}	$I_F = 75 \text{ A}$ $di/dt_{off} = 3750 \text{ A/}\mu\text{s}$ $V_{GE} = -15 \text{ V}$ $V_{CC} = 600 \text{ V}$	T _j = 150 °C		120		Α			
Q _{rr}		T _j = 150 °C		12		μC			
E _{rr}		T _j = 150 °C		3.7		mJ			
R _{th(j-c)}	per diode			0.536	K/W				
R _{th(c-s)}	per diode (λ _{grease} =0.81 W/(m*K))			0.144		K/W			
Module									
L _{CE}				30		nH			
R _{CC'+EE'}	measured per switch	T _C = 25 °C		0.65		mΩ			
		T _C = 125 °C		1.09		mΩ			
R _{th(c-s)1}	calculated without thermal coupling			0.0359		K/W			
R _{th(c-s)2}	including thermal co Ts underneath mod (λ _{grease} =0.81 W/(m*		0.057		K/W				
Ms	to heat sink M6		3		5	Nm			
M _t		to terminals M5	2.5		5	Nm			
				-		Nm			
w					160	g			

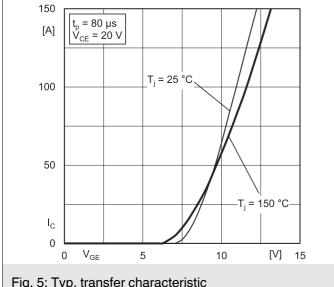












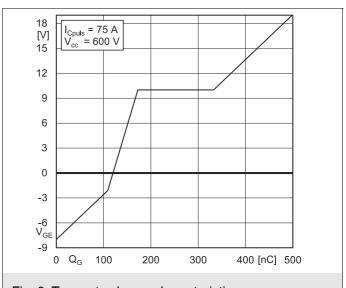
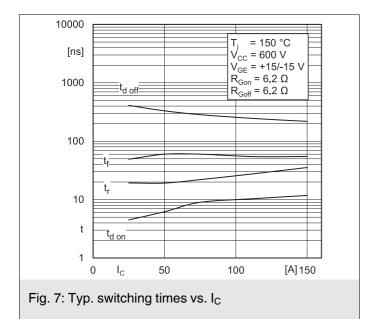
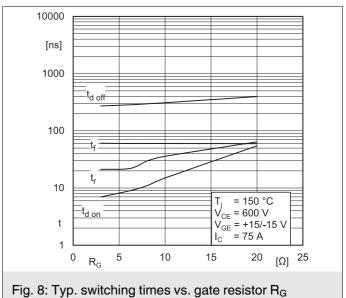
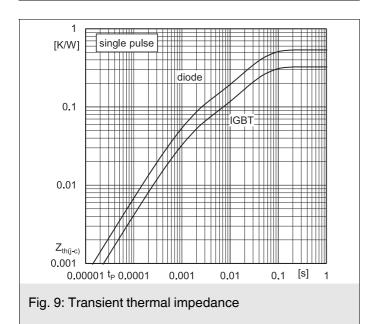
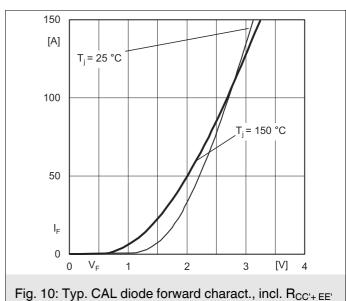


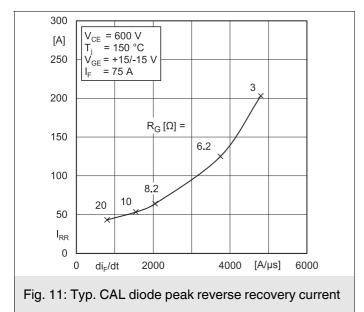
Fig. 5: Typ. transfer characteristic Fig. 6: Typ. gate charge characteristic











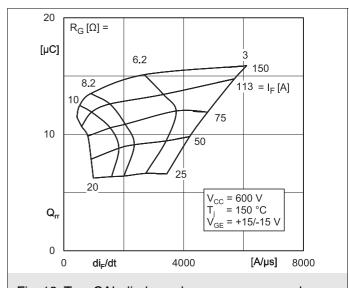
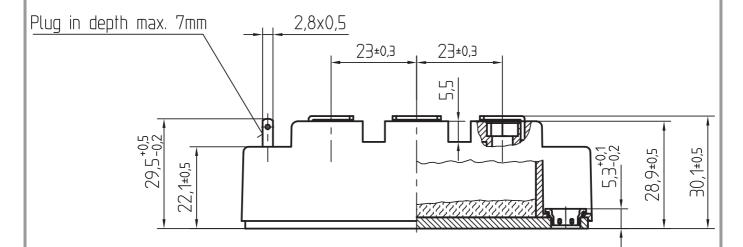
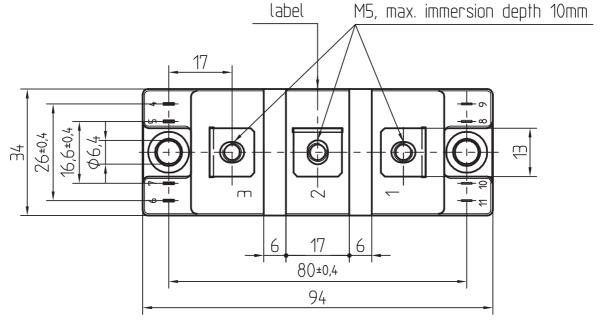


Fig. 12: Typ. CAL diode peak reverse recovery charge

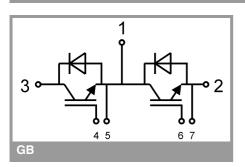






General tolerance +/- 0,5 mm

SEMITRANS 2



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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